INTEGRATED CIRCUIT

TOSHIBA

TECHNICAL DATA

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT

TC74ACT157P/F/FN/FS

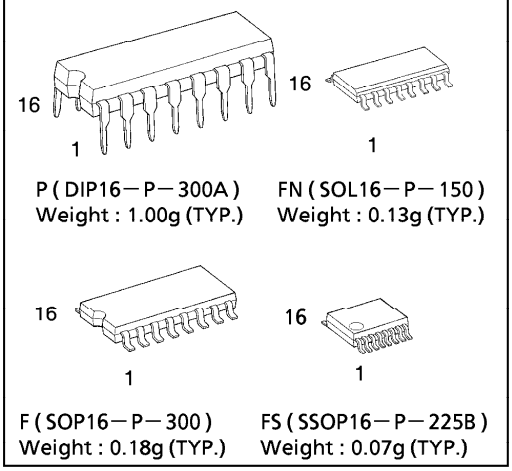
SILICON MONOLITHIC

QUAD 2 – CHANNEL MULTIPLEXER

The TC74ACT157 is an advanced high speed CMOS QUAD 2 - CHANNEL MULTIPLEXER fabricated with silicon gate and double - layer metal wiring C²MOS technology.
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.
This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL,NMOS and CMOS output voltage levles.
This device consist of four 2 - input digital multiplexer with common select and strobe inputs.
When the $\overline{\text{STROBE}}$ input is held "H" level, selection of data is inhibited and all the outputs become "L" level.
The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

- High Speed ..... t_{pd} = 5.1ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ..... I_{CC} = 8μA(Max.) at Ta = 25°C
- Compatible with TTL outputs .... V_{IL} = 0.8V(Max.)
  V_{IH} = 2.0V(Min.)
- Symmetrical Output Impedance ... $|I_{OH}| = I_{OL}$ = 24mA(Min.)
  Capability of driving 50Ω tansmission lines.
- Balanced Propagation Delays ..... $t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with 74F157



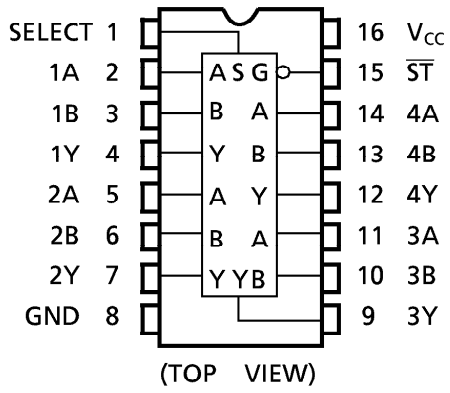
P (DIP16 – P – 300A)
Weight : 1.00g (TYP.)

FN (SOL16 – P – 150)
Weight : 0.13g (TYP.)

F (SOP16 – P – 300)
Weight : 0.18g (TYP.)

FS (SSOP16 – P – 225B)
Weight : 0.07g (TYP.)

PIN ASSIGNMENT



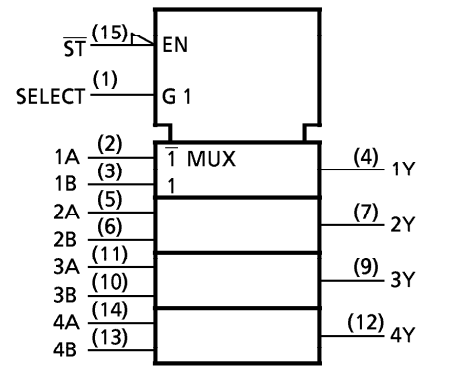
(TOP VIEW)

TRUTH TABLE

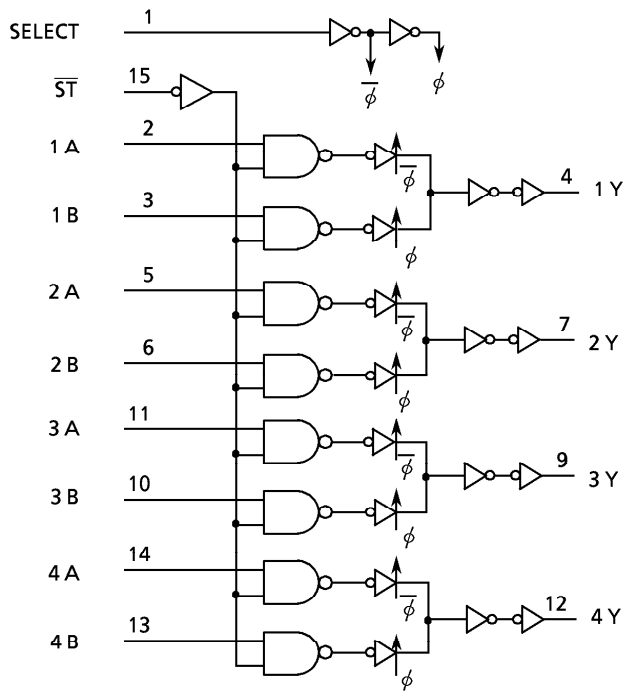
INPUTS				OUTPUTS
$\overline{ST}$	SELECT	A	B	Y
H	X	X	X	L
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

X : Don't Care

IEC LOGIC SYMBOL



SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 50	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC}/Ground Current	I_{CC}	± 100	mA
Power Dissipation	P_D	500 (DIP)*/ 180 (SOP/SSOP)	mW
Storage Temperature	T_{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~10	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			4.5 ~ 5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}			4.5 ~ 5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA	4.5	4.4	4.5	—	4.4	—	V
			I_{OH} = −24mA	4.5	3.94	—	—	3.80	—	
			I_{OH} = −75mA*	5.5	—	—	—	3.85	—	
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 24mA	4.5	—	—	0.36	—	0.44	
			I_{OL} = 75mA*	5.5	—	—	—	—	1.65	
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	8.0	—	80.0	μA
	I_C	PER INPUT : V_{IN} = 3.4V OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.5	mA

* : This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

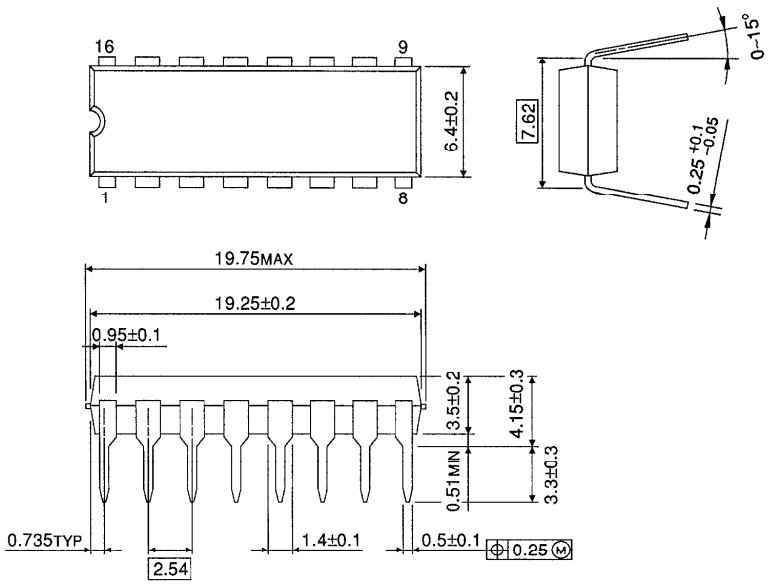
AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, R_L = 500Ω, Input $t_r = t_f$ = 3ns)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
Propagation Delay Time (A, B−Y)	t_{pLH} t_{pHL}		5.0 ± 0.5	—	5.5	8.0	1.0	9.1	ns
Propagation Delay Time (SELECT−Y)	t_{pLH} t_{pHL}		5.0 ± 0.5	—	6.9	11.4	1.0	13.0	
Propagation Delay Time ($\overline{ST}$−Y)	t_{pLH} t_{pHL}		5.0 ± 0.5	—	6.8	10.8	1.0	12.3	
Input Capacitance	C_{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD}			—	51	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :

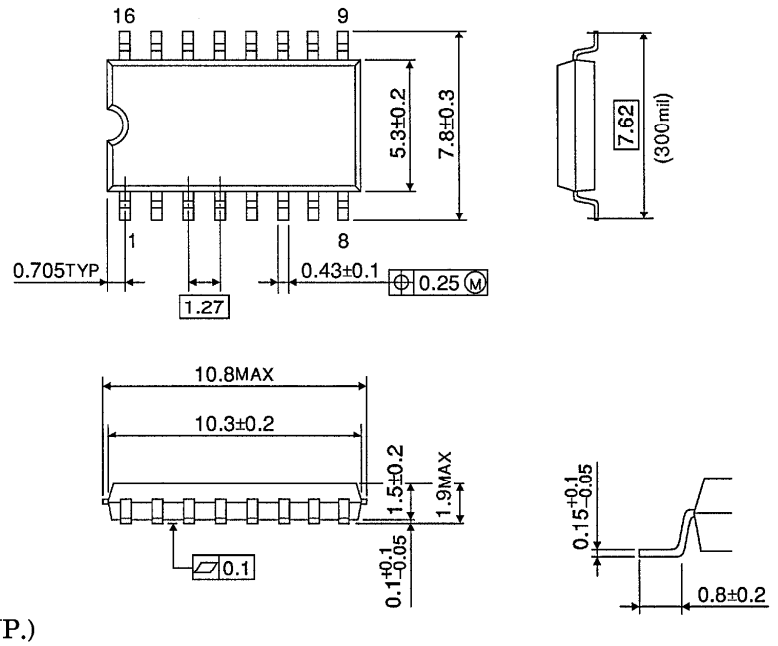
$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 \text{ (per bit)}$$

DIP 16PIN OUTLINE DRAWING (DIP16−P−300A) Unit in mm



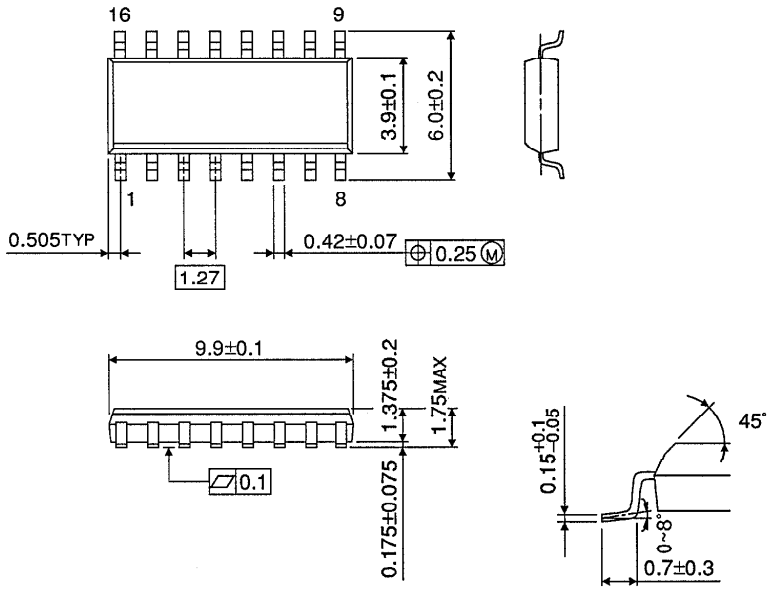
Weight : 1.00g (TYP.)

SOP 16PIN (200mil BODY) OUTLINE DRAWING (SOP16−P−300) Unit in mm



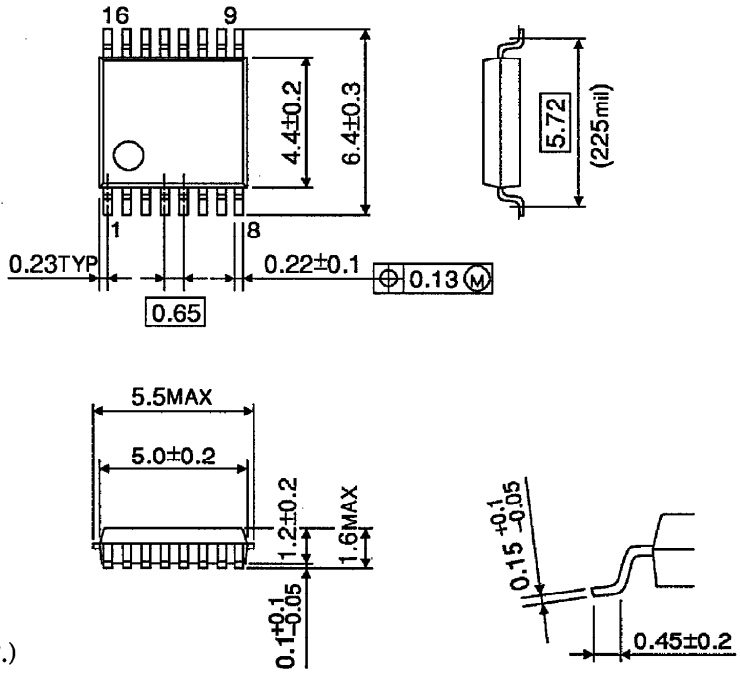
Weight : 0.18g (TYP.)

SOP 16PIN (150mil BODY) OUTLINE DRAWING (SOL16−P−150) Unit in mm



Weight : 0.13g (TYP.)

SSOP 16PIN OUTLINE DRAWING (SSOP16−P−225B) Unit in mm



Weight : 0.07g (TYP.)